PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

Rev. 4 — 7 December 2011

Product data sheet

1. Product profile

1.1 General description

PNP/PNP double Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1.	Product	overview

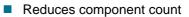
Type number	Package		NPN/PNP	NPN/NPN	Package
	NXP	JEITA	complement	complement	configuration
PEMB13	SOT666	-	PEMD13	PEMH13	ultra small and flat lead
PUMB13	SOT363	SC-88	PUMD13	PUMH13	very small

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- 1.3 Applications
 - Low current peripheral driver
 - Control of IC inputs
 - Replaces general-purpose transistors in digital applications

1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transi	istor					
V _{CEO}	collector-emitter voltage	open base	-	-	-50	V
lo	output current		-	-	-100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		8	10	12	



- Reduces pick and place costs
- AEC-Q101 qualified



1

| | 2 3 006aaa212

PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	GND (emitter) TR1		
2	input (base) TR1		
3	output (collector) TR2		
4	GND (emitter) TR2		
5	input (base) TR2		
6	output (collector) TR1	001aab555	

3. Ordering information

Table 4. Ordering information				
Type number	Package			
	Name	Description	Version	
PEMB13	-	plastic surface-mounted package; 6 leads	SOT666	
PUMB13	SC-88	plastic surface-mounted package; 6 leads	SOT363	

4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
PEMB13	45
PUMB13	B*5

[1] * = placeholder for manufacturing site code

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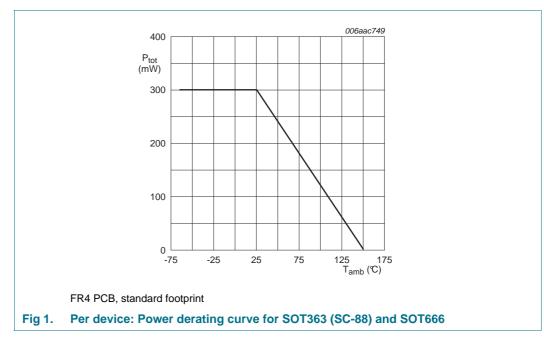
5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor				
V _{CBO}	collector-base voltage	open emitter	-	-50	V
V _{CEO}	collector-emitter voltage	open base	-	-50	V
V _{EBO}	emitter-base voltage	open collector	-	-5	V
VI	input voltage				
	positive		-	+5	V
	negative		-	-30	V
lo	output current		-	-100	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 \text{ ms}$	-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PEMB13 (SOT666)		<u>[1][2]</u> _	200	mW
	PUMB13 (SOT363)		<u>[1]</u> -	200	mW
Per device)				
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PEMB13 (SOT666)		<u>[1][2]</u> _	300	mW
	PUMB13 (SOT363)		<u>[1]</u> -	300	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω



6. Thermal characteristics

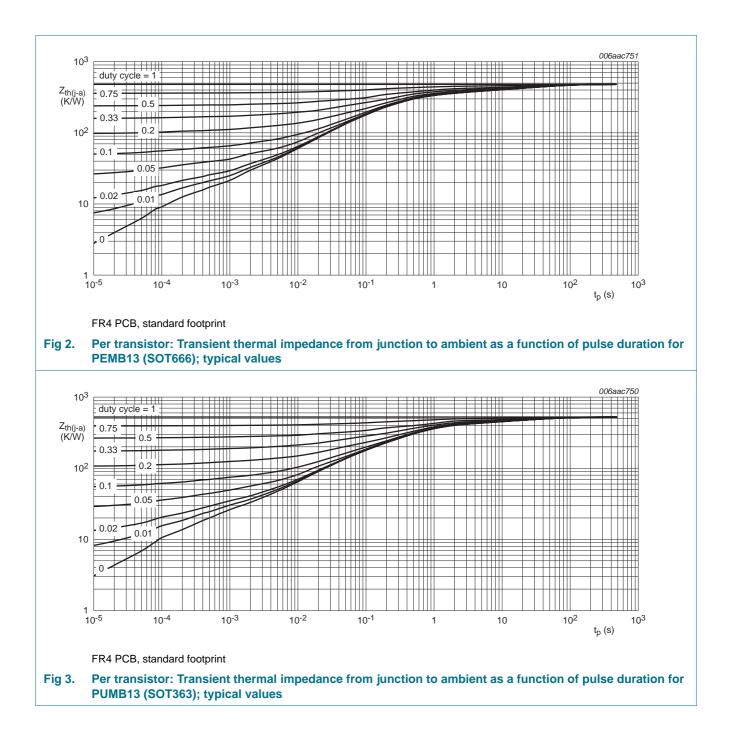
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transi	istor					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	PEMB13 (SOT666)		<u>[1][2]</u> _	-	625	K/W
	PUMB13 (SOT363)		<u>[1]</u> _	-	625	K/W
Per devic	e					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air				
	PEMB13 (SOT666)		[1][2] _	-	417	K/W
	PUMB13 (SOT363)		<u>[1]</u> _	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

PEMB13; PUMB13

PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω



PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

7. Characteristics

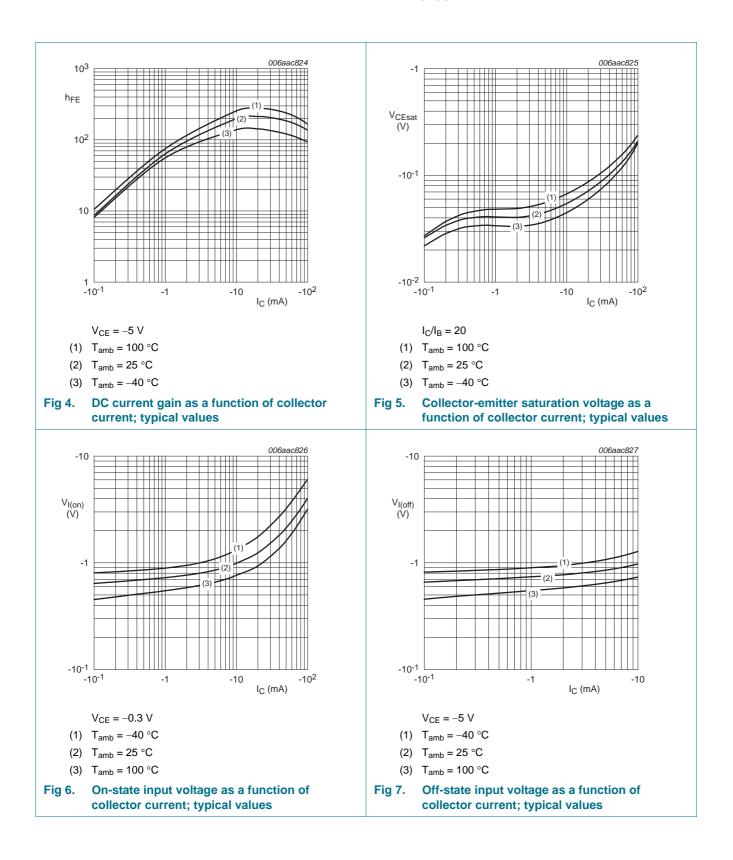
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per trans	istor						
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; \text{ I}_{E} = 0 \text{ A}$		-	-	-100	nA
I _{CEO}	collector-emitter cut-off	$V_{CE} = -30$ V; $I_B = 0$ A		-	-	-1	μA
	current	$\label{eq:Vce} \begin{array}{l} V_{CE} = -30 \ V; \ I_{B} = 0 \ A; \\ T_{j} = 150 \ ^{\circ}C \end{array}$,	-	-	-5	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$,	-	-	-170	μΑ
h _{FE}	DC current gain	V_{CE} = -5 V; I_C = -10 mA		100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = -5 \text{ mA}; I_{B} = -0.25 \text{ mA}$		-	-	-100	mV
V _{I(off)}	off-state input voltage	V_{CE} = –5 V; I_{C} = –100 μA		-	-0.6	-0.5	V
V _{I(on)}	on-state input voltage	V_{CE} = –0.3 V; I_{C} = –5 mA		–1.3	-0.9	-	V
R1	bias resistor 1 (input)			3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio			8	10	12	
C _c	collector capacitance	$\label{eq:VCB} \begin{split} V_{CB} &= -10 \text{ V}; \text{ I}_{E} = \text{ i}_{e} = 0 \text{ A}; \\ \text{ f} &= 1 \text{ MHz} \end{split}$		-	-	3	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -10 \text{ mA};$ f = 100 MHz	<u>[1]</u>	-	180	-	MHz

[1] Characteristics of built-in transistor

PEMB13_PUMB13 Product data sheet

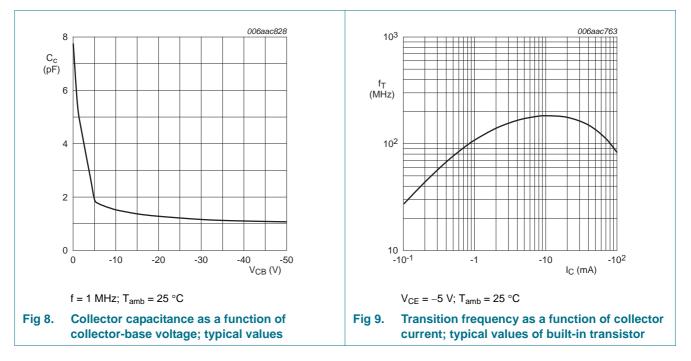
PEMB13; PUMB13

PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω



PEMB13; PUMB13

PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

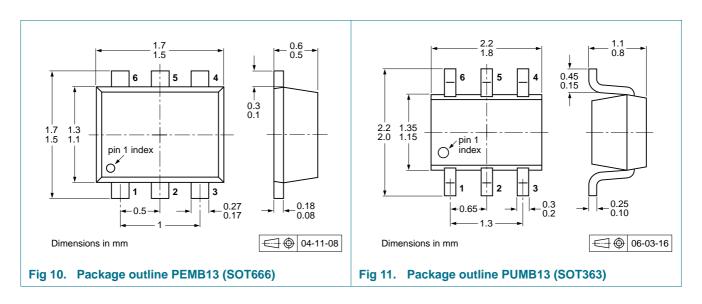


8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



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10. Packing information

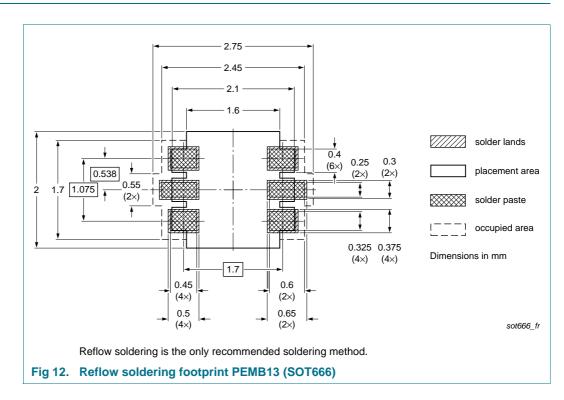
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

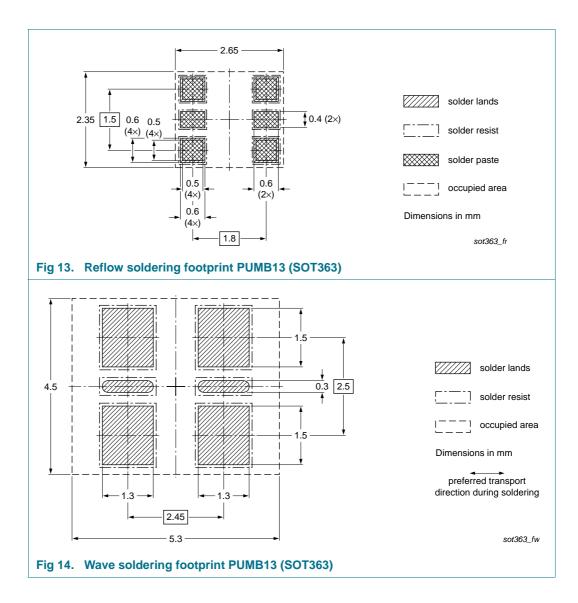
Туре	Package	Description			Packing quantity			
number				3000	4000	8000	10000	
PEMB13	SOT666	2 mm pitch, 8 mm tape and reel		-	-	-315	-	
		4 mm pitch, 8 mm tape and reel		-	-115	-	-	
PUMB13 SOT363		4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-	-	-135	
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-	-	-165	

- [1] For further information and the availability of packing methods, see <u>Section 14</u>.
- [2] T1: normal taping
- [3] T2: reverse taping

11. Soldering



PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω



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PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PEMB13_PUMB13 v.4	20111207	Product data sheet	-	PEMB13_PUMB13 v.3		
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 					
	 Legal texts have been adapted to the new company name where appropriate. 					
	Section 1 "	Product profile": updated				
	 <u>Section 4 "Marking"</u>: updated 					
	• Figure 1 to 9: added					
	 <u>Section 5 "Limiting values"</u>: updated 					
	 Section 6 "Thermal characteristics": updated 					
	• <u>Table 8 "Characteristics</u> ": $V_{i(on)}$ redefined to $V_{I(on)}$ on-state input voltage, $V_{i(off)}$ redefined to $V_{I(off)}$ off-state input voltage, I_{CEO} updated, f_T added					
	<u>Section 8 "Test information"</u> : added					
	 Section 9 "Package outline": superseded by minimized package outline drawings 					
	 Section 10 "Packing information": added 					
	Section 11 "Soldering": added					
	Section 13	"Legal information": updated				
PEMB13_PUMB13 v.3	20040415	Product data sheet	-	PEMB13_PUMB13 v.2		
PEMB13_PUMB13 v.2	20031211	Product specification	-	PEMB13 v.1		
PEMB13 v.1	20020114	Preliminary specification	-	-		

Table 10. Revision history

PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PEMB13_PUMB13

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PNP/PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

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Product data sheet

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1	Product profile 1

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

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